

2SC5006

PNP EPITAXIAL SILICON TRANSISTOR

NPN SILICON EPITAXIAL TRANSISTOR

DESCRIPTION

The UTC 2SC5006 is an NPN epitaxial transistor; it uses UTC's advanced technology to provide the customers with low noise figure, high DC current gain and high current capability achieve a very wide dynamic range and excellent linearity.

The UTC 2SC5006 is suitable for low noise and small signal amplifiers from VHF band to UHF band.

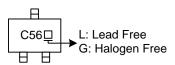
FEATURES

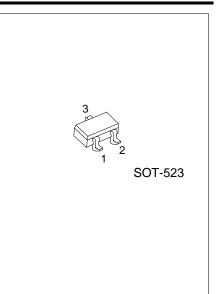
- * High DC current gain
- * High current capability
- * Low noise figure

| | ORDERING INFOR | RMATION | | | | | | |
|----|---|--------------|---------|----------------|---|---|-----------|--|
| | Ordering Number | | Dookogo | Pin Assignment | | | Deaking | |
| | Lead Free | Halogen-Free | Package | 1 | 2 | 3 | Packing | |
| | 2SC5006L-AN3-R 2SC5006G-AN | | SOT-523 | В | Е | С | Tape Reel | |
| No | Note: Pin Assignment: B: Base E: Emitter C: Collector | | | | | | | |

| 2SC5006 <u>G</u> - <u>AN3</u> -R | | |
|----------------------------------|---|--|
| (2)Package Type | R: Tape Reel AN3: SOT-523 G: Halogen Free and Lead Free, L: Lead Free | |

MARKING





■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C, unless otherwise specified)

| PARAMETER | SYMBOL | RATINGS | UNIT |
|---------------------------|------------------|------------|------|
| Collector-Base Voltage | V _{CBO} | 20 | V |
| Collector-Emitter Voltage | V _{CEO} | 12 | V |
| Emitter-Base Voltage | V _{EBO} | 3.0 | V |
| Collector Current | lc | 100 | mA |
| Total Power Dissipation | PT | 125 | mW |
| Junction Temperature | TJ | +150 | °C |
| Storage Temperature | T _{STG} | -60 ~ +150 | °C |

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

| PARAMETER | SYMBOL | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------------------|------------------|---|-----|-----|-----|------|
| Collector Cut-Off Current | I _{CBO} | V _{CB} =10V, I _E =0 | | | 1.0 | μA |
| Emitter Cutoff Current | I _{EBO} | $V_{EB}=1V$, $I_{C}=0$ | | | 1.0 | μA |
| DC Current Gain | h _{FE} | V _{CE} =3V, I _C =7mA (Note 1) | 80 | | 160 | |
| Transition Frequency | f⊤ | V _{CE} =3V, I _C =7mA, f=1GHz | | 4.5 | | GHz |
| Feedback Capacitance | Cre | V _{CB} =3V, I _E =0, f=1.0MHz (Note 2) | | 0.7 | | рF |

Notes: 1. Pulse measurement $P_W \leq 350 \mu s$, duty cycle $\leq 2\%$.

2. The emitter terminal and the case shall be connected to the gurad terminal of the three-terminal capacitance bridge.



UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. UTC reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

